## NSN 5980-01-351-4897

Optoelectronic Coupler - Page 1 of 1



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## **General Description:**

Gallium-arsenide light emitting diode optically coupled to a planar silicon npn darlington phototransistor both of which are in a plastic case; reverse voltage 3.0 volts for I e d; collector-emitter breakdown voltage 30.0 for phototransistor; power dissipation 90.0mw; 0.450 in. Maximum lg; 0.280 in. Maximum w; 0.200 in. Maximum h

A: 10	
Shelf	I ItΦ.
OHEH	LIIC.

N/a

**Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

Fiig:

A23900